In-situ Raman spectroscopy of quartz: A pressure sensor for hydrothermal diamond-anvil cell experiments at elevated temperatures

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ABSTRACT

Changes in frequency and linewidth of the 206 and 464 cm⁻¹ A₁ Raman modes of quartz were determined over temperatures from 23 to 800 °C and simultaneously at pressures ranging between 0.1 MPa and 2.1 GPa using a hydrothermal diamond-anvil cell (HDAC). The frequency shift of the 464 cm⁻¹ peak can be used as a secondary pressure standard for SiO₂-saturated systems in HDAC experiments at temperatures up to 560 °C. The frequency of this peak depends quasilinearly on pressure in the studied pressure range. The global slope $(\partial v_{464}/\partial P)_T$ is 9 ± 0.5 cm⁻¹/GPa. A significant variation of this slope with temperature was not observed. Including literature data, the temperature induced frequency shift of the 464 cm⁻¹ mode is described by $(\Delta v_T)_{464, P=0.1 \text{ MPa}}$ (cm⁻¹) = 2.50136·10⁻¹¹ ·*T*⁴ + 1.46454·10⁻⁸·*T*³ - 1.801·10⁻⁵·*T*² - 0.01216·*T* + 0.29 where -196 ≤ *T* (°C) ≤ 560. The pressure dependence of the linewidth of the 464 cm⁻¹ line increases with temperature. The frequency shifts and linewidths for the 206 cm⁻¹ mode indicate that this line can be used as an alternative to the ruby fluorescence technique as a pressure sensor to about 5 GPa for experiments at room temperature. Both the frequency and linewidth of this mode show significant cross-derivatives ($\partial^2 v_{206}/\partial P\partial T$) and ($\partial^2 FWHM_{206}/\partial P\partial T$).